

## Publikationen 2000

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**Moiré-pattern in LEED obtained by van der Waals epitaxy of lattice mismatched WS<sub>2</sub>/MoTe<sub>2</sub> (0001) heterointerfaces.**

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**Electronic properties of WS<sub>2</sub> monolayer films.**

Thin Solid Films 380(2000) 221-223 R.Rudolph, C. Pettenkofer, A. Klein, W.

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